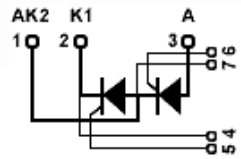
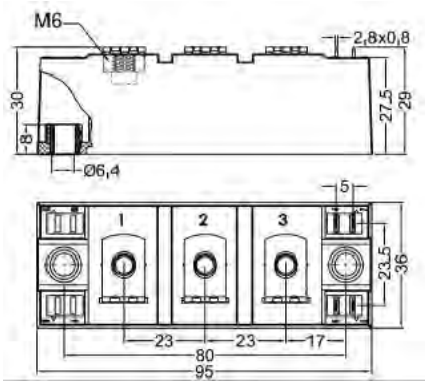
STT130GK**

Thyristor-Thyristor Modules



Type	V_{RSM} V_{DSM} V	V_{RRM} V_{DRM} V
STT130GK08	900	800
STT130GK12	1300	1200
STT130GK14	1500	1400
STT130GK16	1700	1600
STT130GK18	1900	1800

Dimensions in mm (1mm=0.0394")



Symbol	Test Conditions		Maximum Ratings	Unit
I_{TRMS}, I_{FRMS} I_{TAVM}, I_{FAVM}	$T_{VJ}=T_{VJM}$ $T_C=85^oC$; 180° sine		204 130	A
I_{TSM}, I_{FSM}	$T_{VJ}=45^oC$ $V_R=0$	t=10ms (50Hz), sine t=8.3ms (60Hz), sine	4750 5080	A
	$T_{VJ}=T_{VJM}$ $V_R=0$	t=10ms(50Hz), sine t=8.3ms(60Hz), sine	4230 4530	
$\int i^2dt$	$T_{VJ}=45^oC$ $V_R=0$	t=10ms (50Hz), sine t=8.3ms (60Hz), sine	113000 108000	A^2s
	$T_{VJ}=T_{VJM}$ $V_R=0$	t=10ms(50Hz), sine t=8.3ms(60Hz), sine	89500 86200	
$(di/dt)_{cr}$	$T_{VJ}=T_{VJM}$ f=50Hz, t_p=200us $V_D=2/3V_{DRM}$ I_G=0.5A di_G/dt=0.5A/us	repetitive, I_T=500A non repetitive, I_T=500A	150 500	A/us
$(dv/dt)_{cr}$	$T_{VJ}=T_{VJM}$; $R_{GK}=\infty$; method 1 (linear voltage rise)	$V_{DR}=2/3V_{DRM}$	1000	V/us
P_{GM}	$T_{VJ}=T_{VJM}$ $I_T=I_{TAVM}$	t_p=30us t_p=500us	120 60	W
P_{GAV}			8	W
V_{RGM}			10	V
T_{VJ} T_{VJM} T_{stg}			-40...+125 125 -40...+125	°C
V_{ISOL}	50/60Hz, RMS $I_{ISOL}\leq$1mA	t=1min t=1s	3000 3600	V~
M_d	Mounting torque (M6) Terminal connection torque (M6)		2.25-2.75/20-25 4.5-5.5/40-48	Nm/lb.in.
Weight	Typ.		123	g

STT130GK**

Thyristor-Thyristor Modules

Symbol	Test Conditions	Characteristic Values	Unit
I_{RRM}, I_{DRM}	$T_{VJ}=T_{VJM}$; $V_R=V_{RRM}$; $V_D=V_{DRM}$	10	mA
V_{TM}	I_{TM}=390A; T_{VJ}=25°C	1.50	V
V_{TO}	For power-loss calculations only (T_{VJ}=125°C)	0.8	V
r_T		1.5	mΩ
V_{GT}	V_D=6V; T_{VJ}=25°C T_{VJ}=-40°C	2.5 2.6	V
I_{GT}	V_D=6V; T_{VJ}=25°C T_{VJ}=-40°C	150 200	mA
V_{GD}	$T_{VJ}=T_{VJM}$; V_D=2/3V_{DRM}	0.2	V
I_{GD}		10	mA
I_L	T_{VJ}=25°C; t_p=30us; V_D=6V I_G=0.5A; di_G/dt=0.5A/us	300	mA
I_H	T_{VJ}=25°C; V_D=6V; R_{GK}=∞	200	mA
t_{gd}	T_{VJ}=25°C; V_D=1/2V_{DRM} I_G=0.5A; di_G/dt=0.5A/us	2	us
t_q	$T_{VJ}=T_{VJM}$; I_T=160A; t_p=200us; -di/dt=10A/us typ. V_R=100V; dv/dt=20V/us; V_D=2/3V_{DRM}	150	us
Q_S	$T_{VJ}=T_{VJM}$; I_T, I_F=300A; -di/dt=50A/us	550	uC
I_{RM}		235	A
R_{thJC}	per thyristor/diode; DC current per module	0.23 0.115	K/W
R_{thJK}	per thyristor/diode; DC current per module	0.33 0.165	K/W
d_S	Creeping distance on surface	12.7	mm
d_A	Strike distance through air	9.6	mm
a	Maximum allowable acceleration	50	m/s^2

FEATURES
* International standard package
* DBC baseplate
* Glass passivated chips
* Isolation voltage 3600 V~
* UL file NO.310749
* RoHs compliant

APPLICATIONS
* Motor control
* Power converter
* Heat and temperature control for industrial furnaces and chemical processes
* Lighting control
* Contactless switches

ADVANTAGES
* Space and weight savings
* Simple mounting
* Improved temperature and power cycling
* Reduced protection circuits

STT130GK**

Thyristor-Thyristor Modules

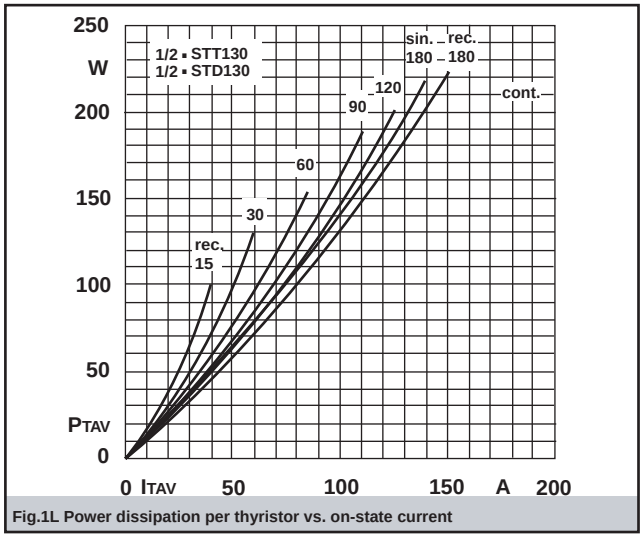


Fig.1L Power dissipation per thyristor vs. on-state current

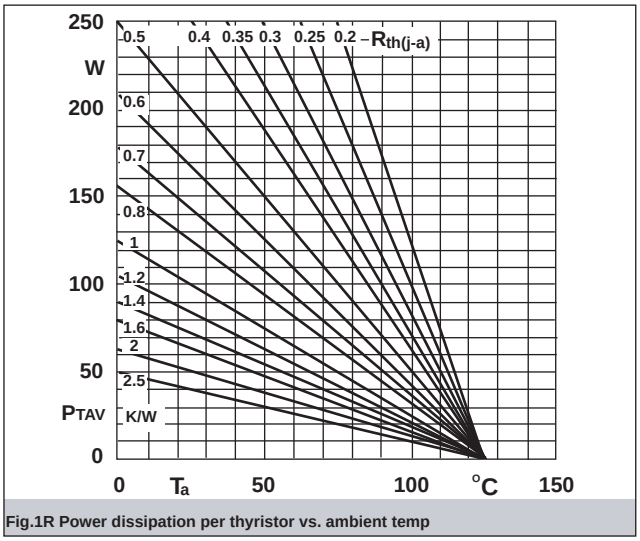


Fig.1R Power dissipation per thyristor vs. ambient temp

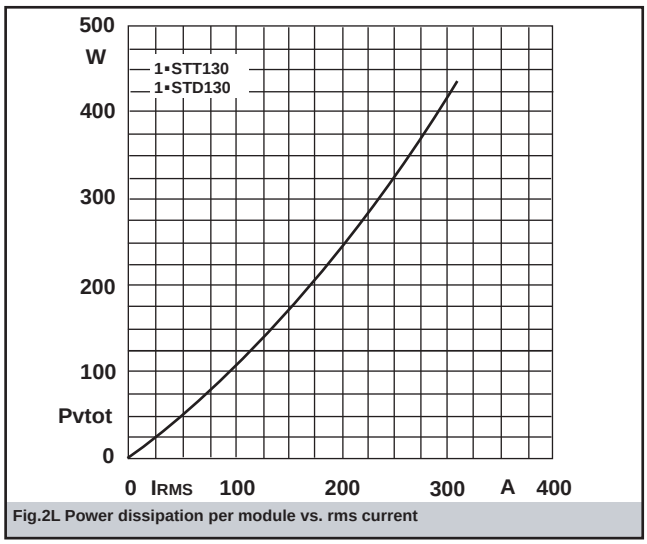


Fig.2L Power dissipation per module vs. rms current

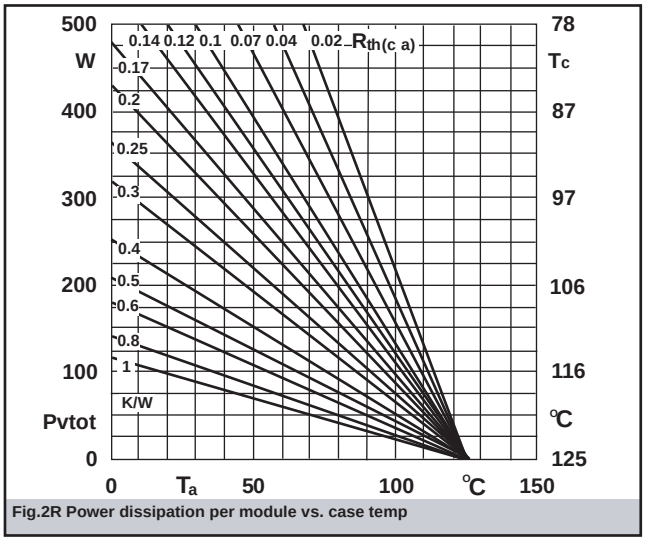


Fig.2R Power dissipation per module vs. case temp

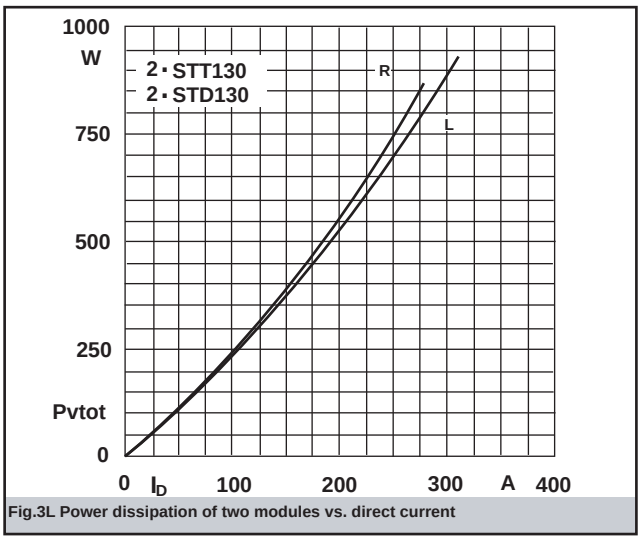


Fig.3L Power dissipation of two modules vs. direct current

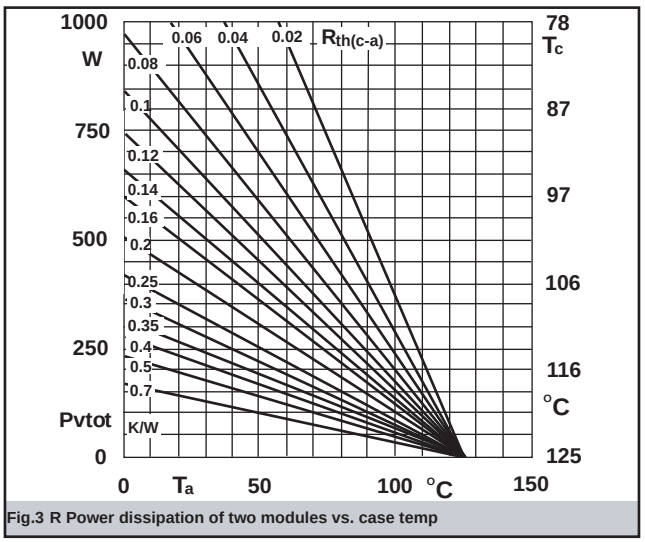


Fig.3 R Power dissipation of two modules vs. case temp

STT130GK**

Thyristor-Thyristor Modules

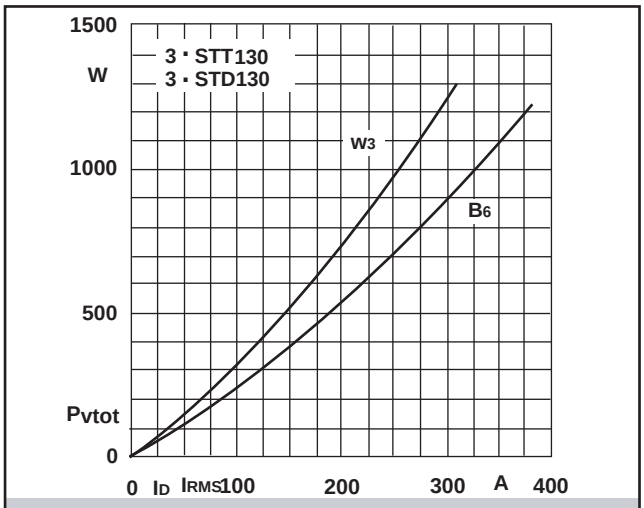


Fig.4L Power dissipation of three modules vs. direct and rms current

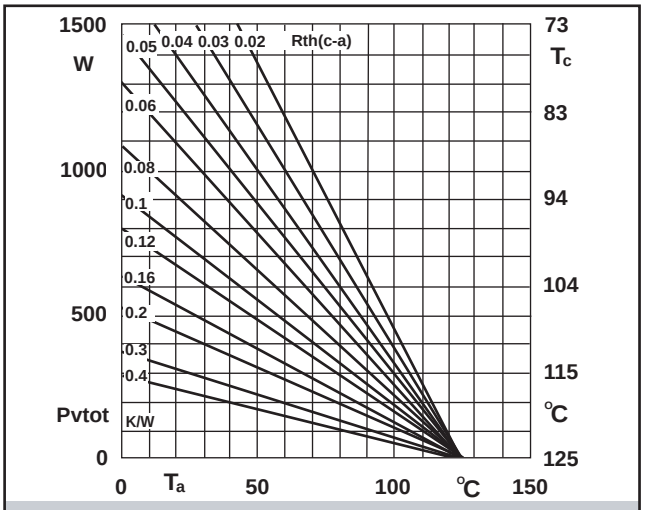


Fig.4R Power dissipation of three modules vs. case temp

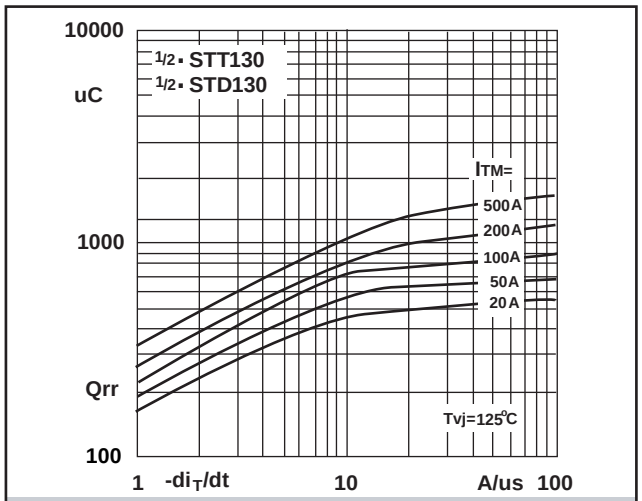


Fig.5 Recovered charge vs. current decrease

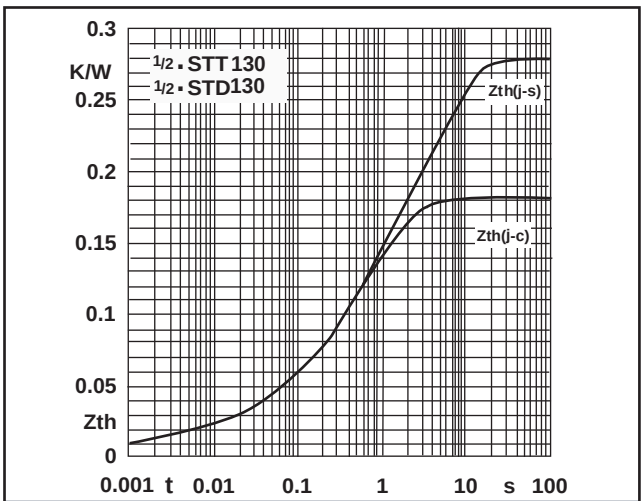


Fig.6 Transient thermal impedance vs. time

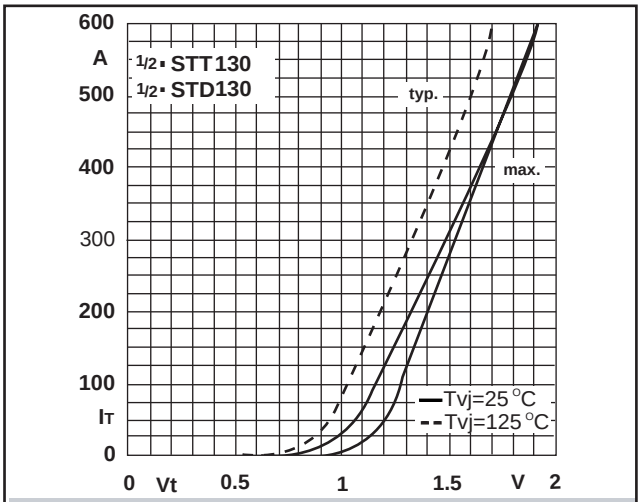


Fig.7 On-state charactristics

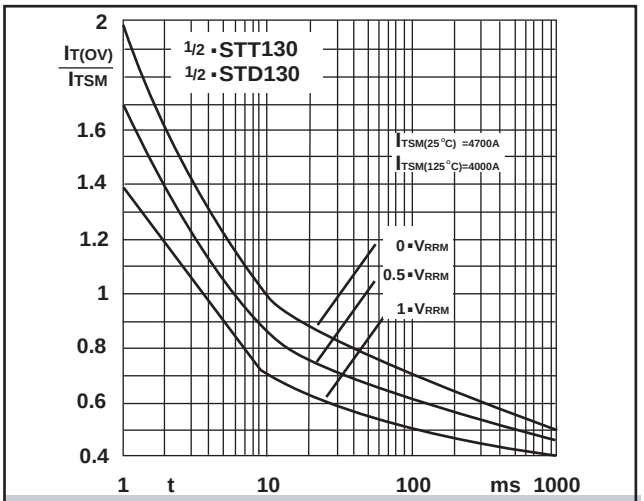


Fig.8 Surge overload current vs. time

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